What is claimed is

- 1. A method for analyzing a semiconductor manufacturing process, comprising:
- (a) generating sets of input and output data from the semiconductor manufacturing process;
- (b) determining principal components from the set of input data by Principal Component Analysis (PCA) and a set of principal component score data based on the principal components; and
- (c) determining a relationship between the sets of input and output data from the set of principal component score data and the set of output data.
- 2. The method of claim 1, further comprising feeding back the relationship to the semiconductor process to predict sets of new input and output data.
- 3. The method of claim 1, wherein the step (a) comprises generating the input and output data from a thermal diffusion process.
- 4. The method of claim 3, further comprising performing the thermal diffusion process in a vertical furnace.
- 5. The method of claim 4, wherein the set of input data comprise different zone temperatures in the vertical furnace.
- 6. The method of claim 4, wherein the set of output data comprise thicknesses of a thin film layer formed by the thermal diffusion process.
- 7. The method of claim 1, further comprising transforming the sets of input and output data into sets of transformed input and output data by a model.
- 8. The method of claim 7, further comprising comparing the sets of input and output data with the sets of transformed input and output data.

- 9. The method of claim 7, wherein the model is an Arrhenius model.
- 10. The method of claim 1, wherein the step (c) comprises applying a regression model to determine the relationship.
- 11. The method of claim 10, wherein the regression model comprises a linear regression model.
- 12. The method of claim 1, further comprising applying design of experiment (DOE) to generate the set of input and output data.
 - 13. A method for analyzing a thermal diffusion process in a vertical furnace, comprising:
 - (a) generating sets of input and output data from the thermal diffusion process by DOE;
- (b) determining principal components from the sets of input data by Principal Component Analysis (PCA) and a set of principal component score data based on the principal components; and
- (c) determining a relationship between the sets of input and output data from the set of principal component score data and the set of output data.
- 14. The method of claim 13, further comprising feeding back the relationship to the semiconductor process for predicting sets of new input and output data.
- 15. The method of claim 13, wherein the set of input data comprise different zone temperatures in the vertical furnace.
- 16. The method of claim 13, wherein the set of output data comprise thicknesses of a thin film layer formed by the thermal diffusion process.
- 17. The method of claim 13, further comprising transforming the sets of input and output data into sets of transformed input and output data by a model.

- 18. The method of claim 17, further comprising comparing the sets of input and output data with the sets of transformed input and output data.
 - 19. The method of claim 17, wherein the model is an Arrhenius model.
- 20. The method of claim 13, wherein the set of principal component score data comprise principal component scores.
- 21. The method of claim 13, wherein the step (c) comprises applying a regression model to determine the relationship.
- 22. The method of claim 21, wherein the regression model comprises a linear regression model.
 - 23. A method for analyzing a thermal diffusion process in a vertical furnace, comprising:
- (a) generating a set of input data having different zone temperatures in the vertical furnace and a set of output data having thicknesses of a thin film layer by DOE;
- (b) transforming the sets of input and output data into sets of transformed input and output data by an Arrhenius model;
- (c) comparing the sets of input and output data with the sets of transformed input and output data;
- (d) determining principal components from the sets of input data by Principal Component Analysis (PCA) and a set of principal component scores based on the principal components;
- (e) determining a relationship between the sets of input and output data from the set of principal component scores and the set of output data by a linear regression model; and
- (f) feeding back the relationship to the semiconductor process to predict sets of new input and output data.
- 24. A system for analyzing a thermal diffusion process in a vertical furnace, comprising, comprising:

at least one storing means adapted to store sets of input data and output data from the semiconductor manufacturing process; and

at least one processor coupled to the storing means, adapted to determine principal components from the sets of input data by Component Analysis (PCA) and a set of principal score data based on the principal components, and determine a relationship between the sets of input and output data from the set of principal component score data and the set of output data.

- 25. The system of claim 24, wherein the processor further is adapted to feed back the relationship to the storing means, and predicts sets of new input and output data.
- 26. The system of claim 24, wherein the set of input data comprise different zone temperatures in the vertical furnace.
- 27. The system of claim 24, wherein the set of output data comprise thicknesses of a dielectric layer formed by the thermal diffusion process.
- 28. The system of claim 24, wherein the processor further is adapted to transform the sets of input and output data into sets of transformed input and output data by a model.
- 29. The system of claim 28, wherein the processor further is adapted to compare the sets of input and output data with the sets of transformed input and output data.
 - 30. The system of claim 28, wherein the model is an Arrhenius model.
- 31. The system of claim 24, wherein the processor is adapted to determine the relationship by using a regression model.
- 32. The system of claim 31, wherein the regression model comprises a linear regression model.
- 33. The system of claim 24, where the sets of input and output data are generated by design of experiment (DOE).